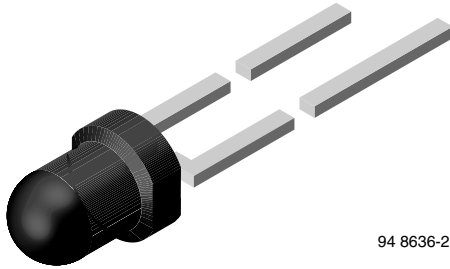


## Silicon NPN Phototransistor



94 8636-2

### DESCRIPTION

TEFT4300 is a silicon NPN phototransistor with high radiant sensitivity in black, T-1 plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

### FEATURES

- Package type: leaded
- Package form: T-1
- Dimensions (in mm):  $\varnothing$  3
- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 30^\circ$
- Package matched with IR emitter series TSUS4300 and TSAL4400
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
**GREEN**  
(5-2008)

### APPLICATIONS

- Optical switches
- Counters and sorters
- Interrupters
- Encoders
- Position sensors

### PRODUCT SUMMARY

| COMPONENT | $I_{ca}$ (mA) | $\varphi$ (deg) | $\lambda_{0.5}$ (nm) |
|-----------|---------------|-----------------|----------------------|
| TEFT4300  | 3.2           | $\pm 30$        | 875 to 1000          |

#### Note

- Test condition see table "Basic Characteristics"

### ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS                      | PACKAGE FORM |
|---------------|-----------|------------------------------|--------------|
| TEFT4300      | Bulk      | MOQ: 5000 pcs, 5000 pcs/bulk | T-1          |

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                           | TEST CONDITION                               | SYMBOL     | VALUE       | UNIT             |
|-------------------------------------|--|------------|-------------|------------------|
| Collector emitter voltage           |  | $V_{CEO}$  | 70          | V                |
| Emitter collector voltage           |  | $V_{ECO}$  | 5           | V                |
| Collector current                   |  | $I_C$      | 50          | mA               |
| Collector peak current              | $t_p/T = 0.5, t_p \leq 10$ ms                | $I_{CM}$   | 100         | mA               |
| Power dissipation                   | $T_{amb} \leq 55^\circ\text{C}$              | $P_V$      | 100         | mW               |
| Junction temperature                |  | $T_j$      | 100         | $^\circ\text{C}$ |
| Operating temperature range         |  | $T_{amb}$  | -40 to +100 | $^\circ\text{C}$ |
| Storage temperature range           |  | $T_{stg}$  | -40 to +100 | $^\circ\text{C}$ |
| Soldering temperature               | $t \leq 3$ s, 2 mm from case                 | $T_{sd}$   | 260         | $^\circ\text{C}$ |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm <sup>2</sup> | $R_{thJA}$ | 450         | K/W              |

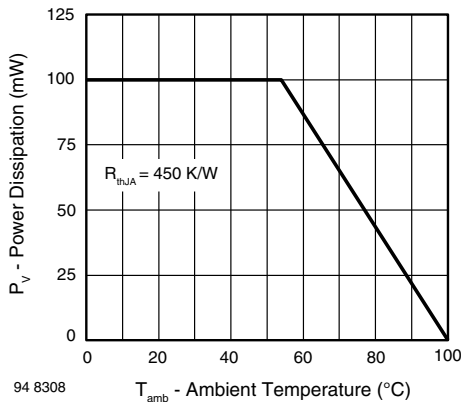


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| <b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |  |                 |      |             |      |               |
|---|--|-----------------|------|-------------|------|---------------|
| PARAMETER   | TEST CONDITION   | SYMBOL          | MIN. | TYP.        | MAX. | UNIT          |
| Collector emitter breakdown voltage   | $I_C = 1\text{ mA}$  | $V_{(BR)CEO}$   | 70   |             |      | V             |
| Collector emitter dark current  | $V_{CE} = 20\text{ V}, E = 0$  | $I_{CEO}$       |      | 1           | 200  | nA            |
| Collector emitter capacitance   | $V_{CE} = 5\text{ V}, f = 1\text{ MHz}, E = 0$                         | $C_{CEO}$       |      | 3           |      | pF            |
| Collector light current   | $E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, V_{CE} = 5\text{ V}$ | $I_{ca}$        | 0.8  | 3.2         |      | mA            |
| Angle of half sensitivity   |  | $\phi$          |      | $\pm 30$    |      | deg           |
| Wavelength of peak sensitivity  |  | $\lambda_p$     |      | 925         |      | nm            |
| Range of spectral bandwidth   |  | $\lambda_{0.5}$ |      | 875 to 1000 |      | nm            |
| Collector emitter saturation voltage  | $E_e = 1\text{ mW/cm}^2, \lambda = 950\text{ nm}, I_C = 0.1\text{ mA}$ | $V_{CEsat}$     |      |             | 0.3  | V             |
| Turn-on time  | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $t_{on}$        |      | 2           |      | $\mu\text{s}$ |
| Turn-off time   | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $t_{off}$       |      | 2.3         |      | $\mu\text{s}$ |
| Cut-off frequency   | $V_S = 5\text{ V}, I_C = 5\text{ mA}, R_L = 100\text{ }\Omega$         | $f_c$           |      | 180         |      | kHz           |

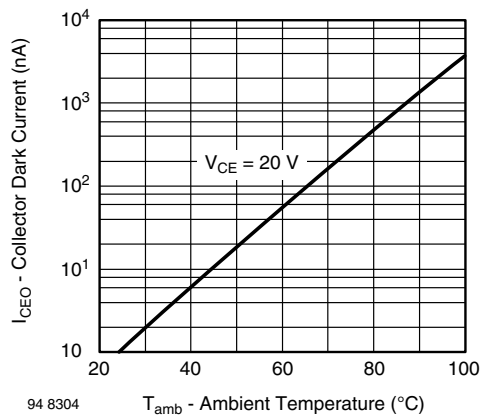
**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)


Fig. 2 - Collector Dark Current vs. Ambient Temperature

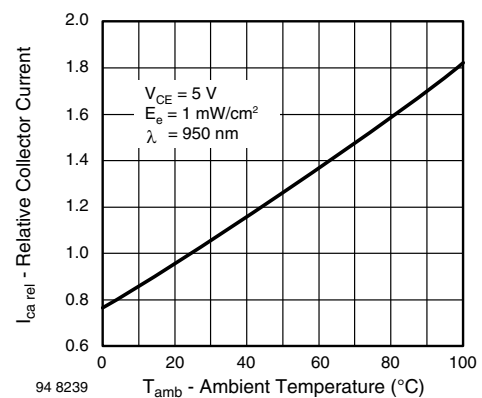


Fig. 3 - Relative Collector Current vs. Ambient Temperature

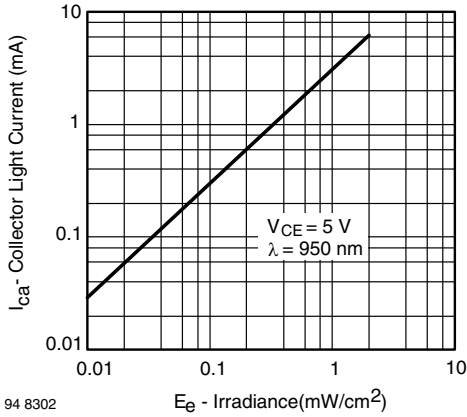


Fig. 4 - Collector Light Current vs. Irradiance

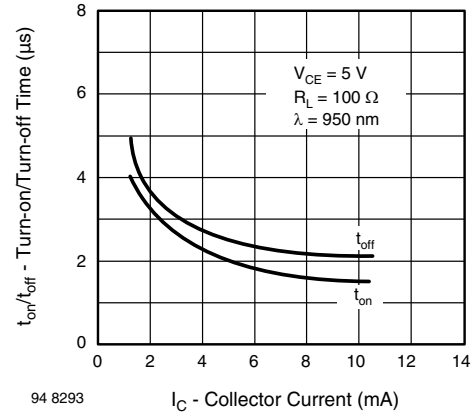


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

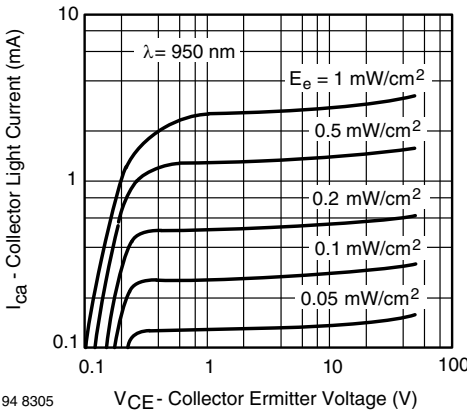


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

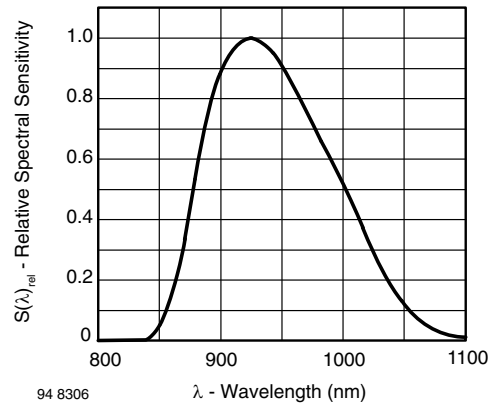


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

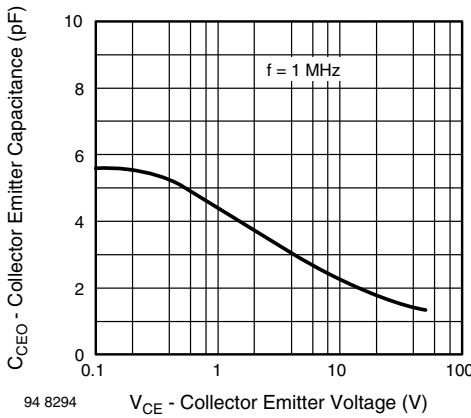


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

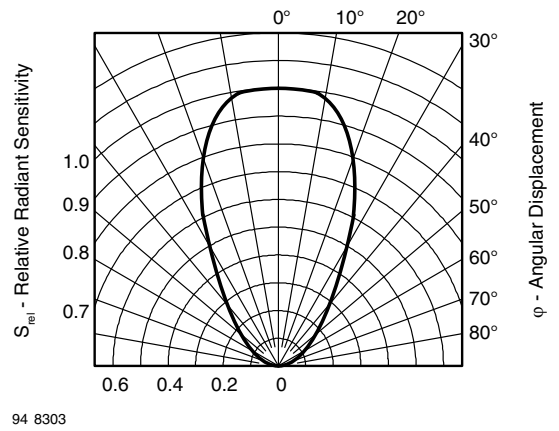
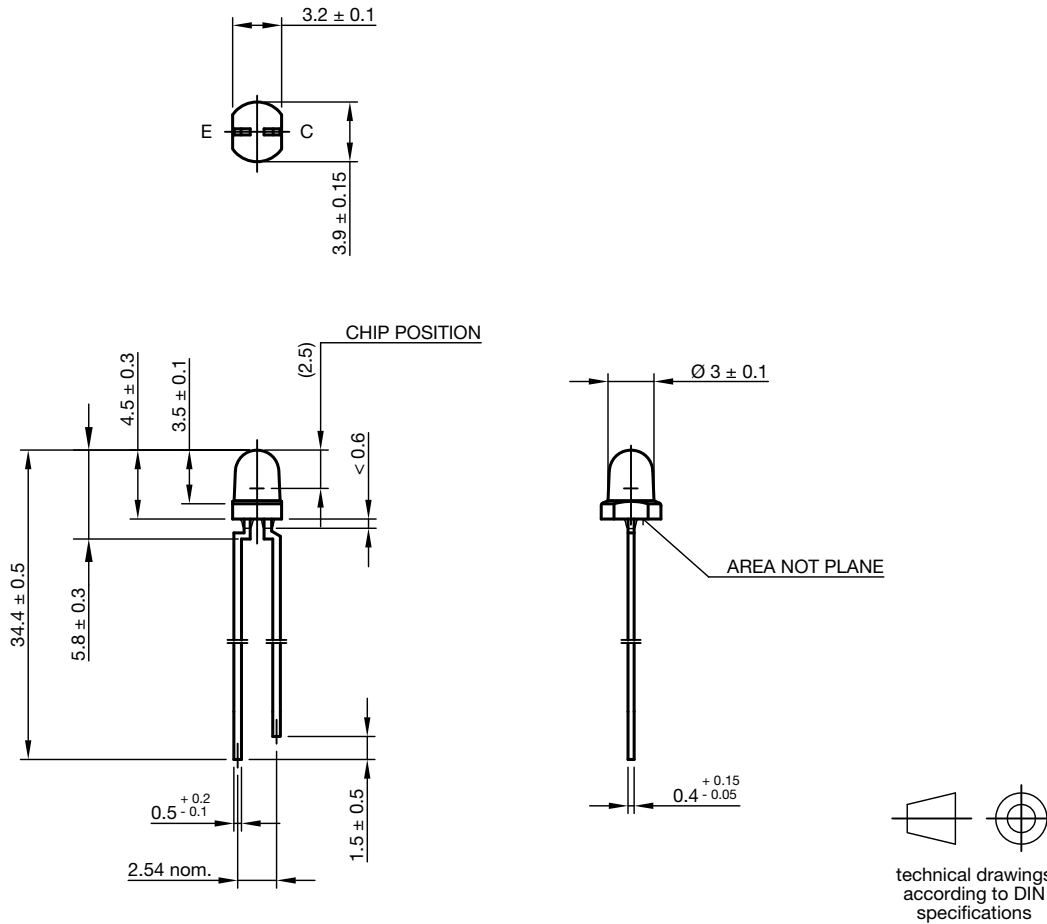


Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement



**PACKAGE DIMENSIONS** in millimeters



Drawing-No.: 6.544-5269.01-4  
Issue: 6; 28.07.14



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